NSN 5962-01-449-6899

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

+0.0/+70.0 degrees celsius

Features Provided:

High speed and static operation and low power

Inclosure Material:

Plastic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Product Name:

Hi speed cmos static ram

Voltage Rating And Type Per Characteristic:

5.0 volts total supply

Time Rating Per Chacteristic:

150.00 nanoseconds af output megawatts

Memory Device Type:

Ram

Terminal Type And Quantity:

28 pin

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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